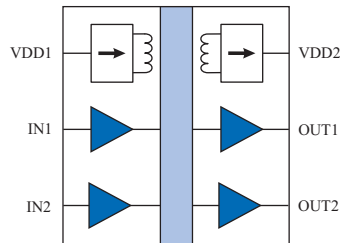
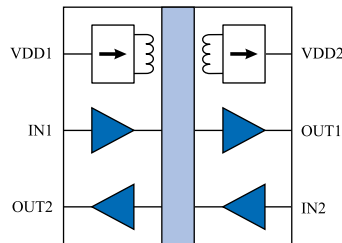


High-Speed Data Couplers with Integrated DC-DC Convertors

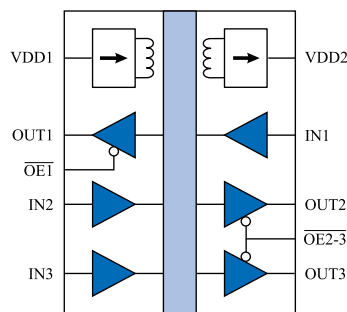
Block Diagrams



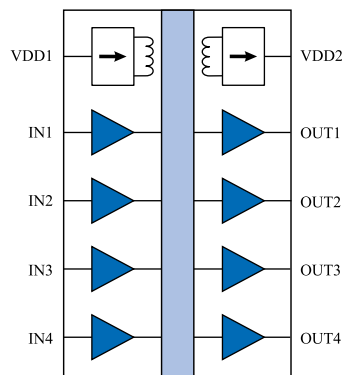
IL7611V



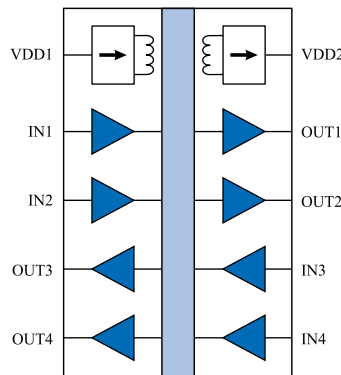
IL7612V



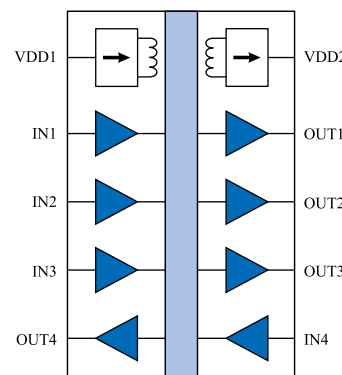
IL7614V



IL7615V



IL7616V



IL7617V

Features

- 110 Mbps
- Integrated ¼ watt, 3.3-to-3.3 V DC-DC convertor
- Ultralow output ripple
- -40 °C to 125 °C temperature range
- Overcurrent and thermal shutdown protection
- Low EMI
- 4 kV_{RMS} isolation
- VDE V 0884-11 (IEC60747-17) certified; UL 1577 approved
- 0.3" True 8TM mm 16-pin SOIC JEDEC-standard package

Applications

- Industrial automation
- IEC 60601 medical instrumentation
- Grid infrastructure
- Test and measurement
- Three-wire SPI
- Isolated ADCs and DACs

Description

The IL76xx-Series are high-speed, fully-isolated, data couplers with integrated 3.3-to-3.3 V, one-quarter watt DC-DC convertors. This level of integration dramatically reduces chip count and board area.

The devices use NVE's proven, patented* spintronic Giant Magnetoresistance (GMR) isolation technology and IsoLoop® high-efficiency micro-scale isolation transformers.

Frequency hopping and integrated shielding minimize EMI.

A unique ceramic/polymer composite barrier provides best-in-class isolation and virtually unlimited barrier life.

Absolute Maximum Ratings⁽¹⁾

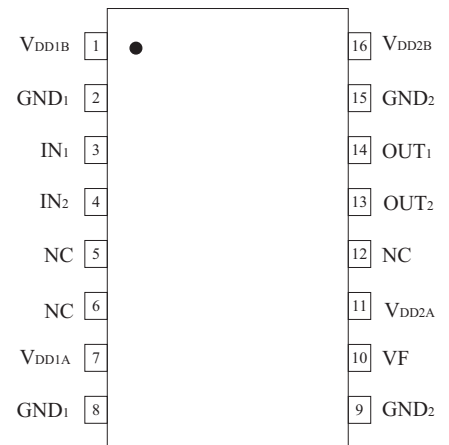
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Storage temperature	T_S	-55		150	°C	
Junction temperature	T_J	-55		150	°C	
Supply voltage	V_{DD1}	-0.5		6	V	
Digital input voltage		-0.5		$V_{DD} + 0.5$	V	
Digital output voltage		-0.5		$V_{DD} + 1$	V	
Coupler output current drive	I_O			10	mA	
Lead solder temperature				260	°C	10 sec.
ESD			2		kV	HBM

Recommended Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Input-side supply voltage	V_{DD1}	3	3.3	3.6	V	
Isolated-side power supply input	V_{DD2B}	2.7	3.3	5.5	V	
Ambient operating temperature	$T_{min}; T_{max}$	-40		125	°C	
Junction temperature	T_J	-40		150	°C	
High-level digital input voltage	V_{IH}	2.4		V_{DD1}	V	$V_{DD1} = 3.3$ V
Low-level digital input voltage	V_{IL}	0		0.8	V	

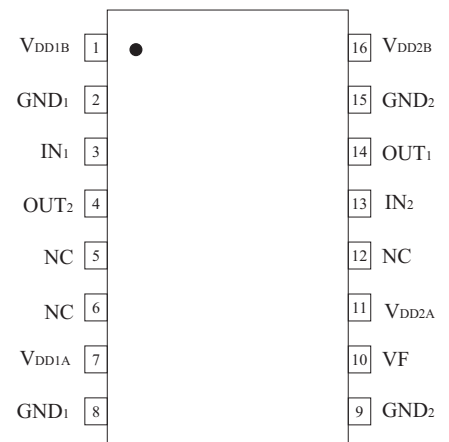
IL7611V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
3	IN ₁	Data in, channel 1
4	IN ₂	Data in, channel 2
5	NC	No internal connection
6	NC	No internal connection
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μF.
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μF/16 V external filter capacitor.
11	V _{DD2A}	Isolated DC-DC convertor output
12	NC	No internal connection
13	OUT ₂	Data out, channel 1
14	OUT ₁	Data out, channel 2
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
16	V _{DD2B}	Isolated-side power supply input (connect to pin 11 and bypass with 10 μF for normal operation).



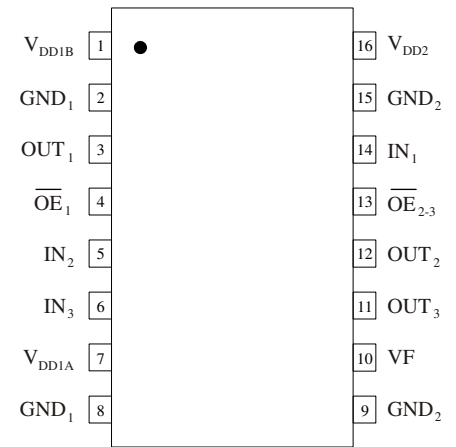
IL7612V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
3	IN ₁	Data in, channel 1
4	OUT ₂	Data out, channel 2
5	NC	No internal connection
6	NC	No internal connection
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μF.
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μF/16 V external filter capacitor.
11	V _{DD2A}	Isolated DC-DC convertor output
12	NC	No internal connection
13	IN ₂	Data out, channel 1
14	OUT ₁	Data in, channel 2
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
16	V _{DD2B}	Isolated-side power supply input (connect to pin 11 and bypass with 10 μF for normal operation).



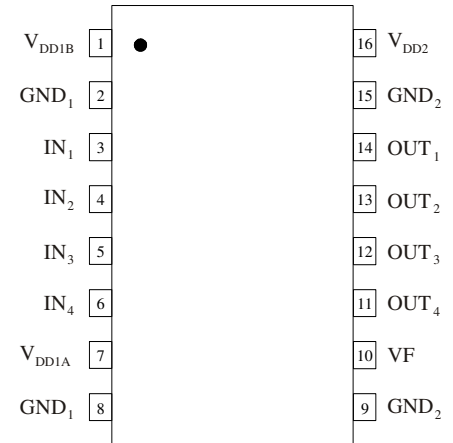
IL7614V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected)
3	OUT ₁	Data out, channel 1
4	$\overline{\text{OE}}_1$	Channel 1 output enable (if high, OUT ₁ = high impedance; has a 500 k Ω nominal internal pulldown)
5	IN ₂	Data in, channel 2
6	IN ₃	Data in, channel 3
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μF .
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected)
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected)
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μF /16 V external filter capacitor.
11	OUT ₃	Data out, channel 3
12	OUT ₂	Data out, channel 2
13	$\overline{\text{OE}}_{2,3}$	Channel 2 and 3 output enable (if high, OUT ₂ and OUT ₃ are high impedance; has a 500 k Ω nominal internal pulldown)
14	IN ₁	Data in, channel 1
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected)
16	V _{DD2}	Isolated supply voltage (bypass with 10 μF).



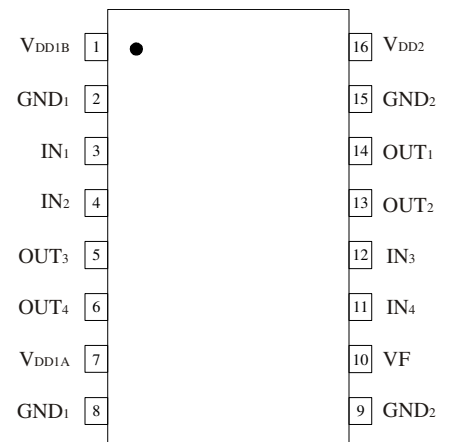
IL7615V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
3	IN ₁	Data in, channel 1
4	IN ₂	Data in, channel 2
5	IN ₃	Data in, channel 3
6	IN ₄	Data in, channel 4
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μ F.
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μ F/16 V external filter capacitor.
11	OUT ₄	Data out, channel 4
12	OUT ₃	Data out, channel 3
13	OUT ₂	Data out, channel 2
14	OUT ₁	Data out, channel 1
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
16	V _{DD2}	Isolated supply voltage (bypass with 10 μ F).



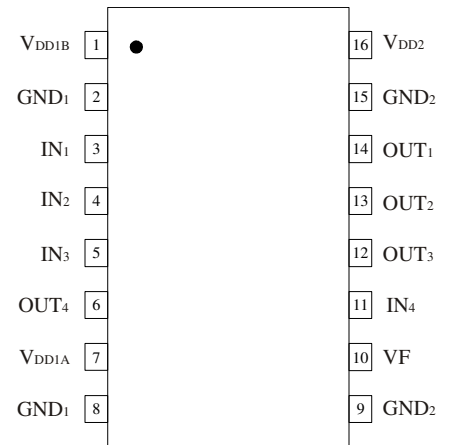
IL7616V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
3	IN ₁	Data in, channel 1
4	IN ₂	Data in, channel 2
5	OUT ₃	Data out, channel 4
6	OUT ₄	Data out, channel 4
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μ F.
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μ F/16 V external filter capacitor.
11	IN ₄	Data in, channel 4
12	IN ₃	Data in, channel 3
13	OUT ₂	Data out, channel 2
14	OUT ₁	Data out, channel 1
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
16	V _{DD2}	Isolated supply voltage (bypass with 10 μ F).



IL7617V Pin Connections

1	V _{DD1B}	Coupler controller-side power supply input (3.3 V nominal).
2	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
3	IN ₁	Data in, channel 1
4	IN ₂	Data in, channel 2
5	IN ₃	Data in, channel 3
6	OUT ₄	Data out, channel 4
7	V _{DD1A}	DC-DC convertor input voltage (3.3 V nominal); bypass with 0.1 μ F.
8	GND ₁	Ground return for V _{DD1} (pins 2 and 8 internally connected).
9	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
10	VF	Output-side rectifier output / regulator input; connect to a 0.1 μ F/16 V external filter capacitor.
11	IN ₄	Data in, channel 4
12	OUT ₃	Data out, channel 3
13	OUT ₂	Data out, channel 2
14	OUT ₁	Data out, channel 1
15	GND ₂	Ground return for V _{DD2} (pins 9 and 15 internally connected).
16	V _{DD2}	Isolated supply voltage (bypass with 10 μ F)



Coupler Specifications ($V_{DD} = 3.3\text{ V}$; T_{min} to T_{max} unless otherwise stated)

Electrical Specifications						
Parameters	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Controller-side coupler quiescent supply current						
IL7611V	I _{DD1B}		0.01	0.015	mA	
IL7612V			1.2	1.75		
IL7614V			1.2	1.75		
IL7615V			0.3	0.4		
IL7616V			2.4	3.5		
IL7617V			1.2	1.75		
Isolated-side quiescent supply current						
IL7611V	I _{DD2}		2.4	3.5	mA	
IL7612V			1.2	1.75		
IL7614V			2.4	3.5		
IL7615V			4.8	7		
IL7616V			2.4	3.5		
IL7617V			3.6	5.25		
Controller-side dynamic supply current						
IL7611V	I _{DD1B}		0.3	0.5	mA/Mbps	All channels switching
IL7612V			0.15	0.25		
IL7614V			0.3	0.5		
IL7615V			0.6	1		
IL7616V			0.3	0.5		
IL7617V			0.45	0.75		
Isolated-side dynamic supply current						
IL7611V	I _{DD2}		0.02	0.04	mA/Mbps	All channels switching
IL7612V			0.15	0.25		
IL7614V			0.15	0.25		
IL7615V			0.02	0.04		
IL7616V			0.3	0.5		
IL7617V			0.15	0.25		
Logic input current	I _I	-10		10	μA	
Logic high output voltage	V _{OH}	$V_{DD} - 0.1$ $0.8 \times V_{DD}$	V_{DD} $0.9 \times V_{DD}$		V	I _O = -20 μA, V _I = V _{IH} I _O = -4 mA, V _I = V _{IH}
Logic low output voltage	V _{OL}		0 0.5	0.1 0.8	V	I _O = 20 μA, V _I = V _{IL} I _O = 4 mA, V _I = V _{IL}

Coupler Switching Specifications						
Maximum data rate		100	110		Mbps	C _L = 15 pF
Pulse width ⁽⁶⁾	PW	10			ns	50% Points, V _O
Propagation delay input to output (high to low)	t _{PHL}		12	18	ns	C _L = 15 pF
Propagation delay input to output (low to high)	t _{PLH}		12	18	ns	C _L = 15 pF
Pulse width distortion ⁽²⁾	PWD		2	3	ns	C _L = 15 pF
Propagation Delay difference between any two parts ⁽³⁾	t _{PSK}		4	6	ns	C _L = 15 pF
Output rise time (10%–90%)	t _r		2	4	ns	C _L = 15 pF
Output fall time (10%–90%)	t _f		2	4	ns	C _L = 15 pF
Common mode transient immunity (output logic high or logic low) ⁽⁴⁾	CM _H , CM _L	30	50		kV/μs	V _{CM} = 1500 V _{DC} t _{TRANSIENT} = 25 ns
Channel-to-channel skew	t _{CSK}		2	3	ns	C _L = 15 pF

Coupler Magnetic Field Immunity ⁽⁷⁾						
Power frequency magnetic immunity	H _{PF}	1000	1500		A/m	50Hz/60Hz
Pulse magnetic field immunity	H _{PM}	1800	2000		A/m	t _p = 8μs
Damped oscillatory magnetic field	H _{OSC}	1800	2000		A/m	0.1Hz – 1MHz
Cross-axis immunity multiplier ⁽⁸⁾	K _X		2.5			

DC-DC Convertor Specifications

T _{min} to T _{max} and V _{DD1} = 3.0 V to 3.6 V unless otherwise stated						
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Output voltage	V _{DD2A}	2.7	3.3	3.45	V	I _{DD2A} < 80 mA
Output current (total available to internal transceiver and external load)	I _{DD2A}	65			mA	
Overcurrent threshold	I _{DD2A}		150		mA	Disable
			145			Re-enable
Short-circuit protection limited current		115	125	135	mA	
Controller-side quiescent supply current	I _{DD1AQ}		200	240	mA	No external load on V _{DD2}
Controller-side supply current	I _{DD1A}		380	440	mA	Maximum DC-DC convertor load
Line regulation	$\Delta V_{DD2}/\Delta V_{DD1A}$		32	40	mV/V	25 °C
			16			125 °C
Load regulation	$\Delta V_{DD2}/V_{DD2}$		5	6	%	I _{DD2} = 0 to max.
Output voltage temperature coefficient	$(\Delta V_{DD2}/V_{DD2}) / \Delta T$		0.017 0.03		%/C	I _{DD2} = 10 mA I _{DD2} = 50 mA
Capacitive load	C _{DD2}			1000	μF	
Output voltage ripple	V _{DD2-RIPPLE}			5	mV _{P-P}	20 MHz bandwidth; I _{DD2} = max.
			1			1 kHz bandwidth; I _{DD2} = max.
Start-up current	I _{DD1-SU}		600	750	mA	700 ns max.
Start-up time	t _{SU}		200		μs	No load
			400			Full load (resistive)
Convertor frequency	f _{OSC}	105	113	120	MHz	

Isolation Specifications

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Isolation voltage*	V_{ISO}	5000			V_{RMS}	Per VDE V 0884-11
Transient overvoltage	V_{IOTM}	6000			V_{PK}	
Surge immunity		12800			V_{PK}	
Creepage distance (external)		8.03	8.3		mm	Per IEC 60601
Total barrier thickness (internal)		0.012	0.016		mm	
Barrier resistance	R_{IO}		$>10^{14}$		Ω	500 V_{RMS}
Barrier capacitance	C_{IO}		7		pF	f = 1 MHz
Leakage current			0.2		μA_{RMS}	240 V_{RMS} , 60 Hz
Comparative tracking index	CTI	≥ 600			V_{RMS}	Per IEC 60112
Barrier life			44000		Years	100°C, 1000 V_{RMS} , 60% CL activation energy

* VDE V 0884-11 Basic Isolation certified under VDE File Number 5016933-4880-0001.

UL 1577 approved under Component Recognition Program File Number E207481.

Parts 100% tested at 4.8 kV_{RMS} (6.79 kV_{PK}) for 1 second, 5 pC partial discharge limit under the stringent IEC60747-17 standard.

Each lot sample tested at 4 kV_{RMS} (5.66 kV_{PK}) for 1 minute.

Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Junction–ambient thermal resistance	θ_{JA}		67		°C/W	Double-sided PCB with thermal vias in free air
Junction–case (top) thermal resistance	θ_{JC}		12			
Junction–ambient thermal resistance	θ_{JA}		46			2s2p PCB with thermal vias per JESD51 with thermal vias in free air
Junction–case (top) thermal resistance	θ_{JC}		9			
Power dissipation	P_D			1.6	W	

Notes:

- Absolute Maximum specifications mean the device will not be damaged if operated under these conditions. It does not guarantee performance.
- PWD is defined as $t_{PHL} - t_{PLH}$. %PWD is equal to PWD divided by pulse width.
- t_{PSK} is the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} between devices at 25 °C.
- CM_H is the maximum common mode voltage slew rate that can be sustained while maintaining $V_O > 0.8 V_{DD2}$. CM_L is the maximum common mode input voltage that can be sustained while maintaining $V_O < 0.8 V$. The common mode voltage slew rates apply to both rising and falling common mode voltage edges.
- Device is considered a two-terminal device: pins 1–8 shorted and pins 9–16 shorted.
- Minimum pulse width is the minimum value at which specified PWD is guaranteed.
- The relevant test and measurement methods are given in the Electromagnetic Compatibility section.
- External magnetic field immunity is improved by this factor if the field direction is “end-to-end” rather than to “pin-to-pin” (see diagram in the Electromagnetic Compatibility section).

Device Operation

DC-DC Converter Operation

The DC-DC converter block diagram is shown in Figure 1:

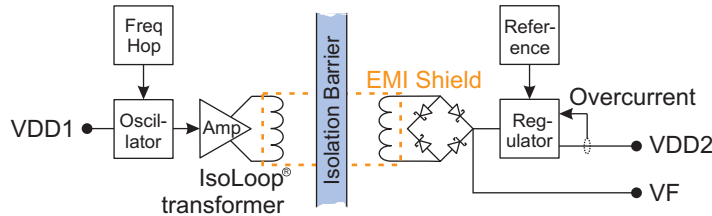


Figure 1. DC-DC converter block diagram.

A 113 MHz oscillator drives a high-frequency power amplifier, which in turn drives an IsoLoop[®] microtransformer primary. Frequency hopping reduces EMI peak amplitudes, and embedded magnetic shielding further reduces radiated EMI.

A unique ceramic/polymer composite barrier provides best-in-class 5 kV isolation with virtually unlimited barrier life.

On the other side of the isolation barrier, the transformer secondary output is filtered, rectified, and regulated by a low-EMI low drop-out regulator with a precision bandgap voltage reference.

Simple Capacitive Decoupling

The only external parts required are a 0.1 μF capacitor placed as close as possible to the V_{DD1B} supply pin, a 10 μF ceramic capacitor for the V_{DD2} pin, and a 0.1 μF/16 V filter capacitor near the V_F pin. The low external parts count reduces board area and cost.

Start-Up Current

The input power supply to the DC-DC converter must be able to supply a start-up surge current of 750 mA for at least 700 ns for the DC-DC converter to start up properly. If the input current is supplied by a regulator, a one-amp regulator provides adequate current.

Short-Circuit Protection

The output current is internally limited to approximately 125 mA. This provides short-circuit protection and eliminates the need for external protection circuitry.

GMR Isolator Operation

An equivalent circuit for each of the Giant Magnetoresistor (GMR) isolator channels is shown in Figure 2:

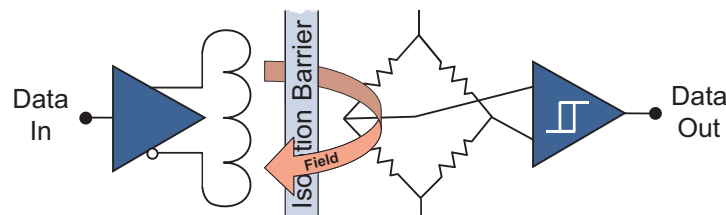


Figure 2. Isolator model signal path.

The GMR isolator signal path starts with a buffered input signal that is driven through an ultraminiature coil. This generates a small magnetic field that changes the electron spin polarization of GMR resistors, which are configured as a Wheatstone bridge. The change in spin polarization of the resistors creates a bridge voltage which drives an output comparator to construct an isolated version of the input signal. GMR is inherently high speed and low distortion.

Dynamic Power Consumption

NVE Isolators achieve their low power consumption from the way they transmit data across the isolation barrier. By detecting the edge transitions of the input logic signal and converting these to narrow current pulses, a magnetic field is created around the GMR Wheatstone bridge. Depending on the direction of the magnetic field, the bridge causes the output comparator to switch following the input logic signal. Since the current pulses are narrow, about 2.5 ns, the power consumption is independent of mark-to-space

ratio and solely dependent on frequency. This has obvious advantages over optocouplers, which have power consumption heavily dependent on mark-to-space ratio.

Power consumption increases with frequency for the input side of each channel, but output-side power consumption is constant for a particular isolator channel. For channels with inputs on the V_{DD2} side, the dynamic power consumption must be provided by the DC-DC convertor, so V_{DD1B} supply current increases with the frequency of that channel.

Current Drawn from the Output of the DC-DC Convertor by the Coupler Section

The current drawn from the output of the DC-DC convertor by the coupler section consists of the coupler's isolated-side quiescent current, plus, in the case of the IL7614V, isolated-side dynamic current. So, for example, for an IL7614V, the isolated-side quiescent current is 3.5 mA, the dynamic current is 0.24 mA/Mbps, so if the coupler is running at 100 Mbps, the dynamic current is 24 mA and the total current is 27.5 mA. Since the DC-DC convertor can supply up to 80 mA, the IL7614 can therefore supply up to 52.5 mA to external loads. Of course, the DC-DC convertor can supply more if the coupler channels are running below full speed.

Optional External Regulation

An external regulator can be used in place of the parts' internal low drop-out regulator for voltages up to approximately 8 volts. The maximum output current decreases at higher regulator output voltages, but the output power capacity remains approximately 250 milliwatts.

Maintaining Creepage

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.

Coupler Status on Start-up and Shut Down

To minimize power dissipation, coupler input signals are differentiated and then latched on the output side of the isolation barrier to reconstruct the signal. This could result in an ambiguous output state depending on power up, shutdown and power loss sequencing. Therefore, the designer should consider including an initialization signal in the start-up circuit. Initialization consists of toggling the input either high then low, or low then high.

Power and Thermal Management

Note that self-heating generated by the quiescent current of the DC-to-DC convertor generally limits the ambient operating temperature to less than 125 °C to avoid exceeding the 150 °C Absolute Maximum junction temperature. The isolator section will operate at 125 °C, however, if the DC-to-DC convertor is not used or is duty cycled.

The IL76xx typically operates well within the current limits of the DC-DC convertor unless the coupler is operating at high speed or there are external loads on the DC-DC convertor. Internal thermal management circuitry gradually limits the output voltage and power output as the junction temperature increases to avoid thermal overload. The coupler section is guaranteed to operate at the 2.7 volt minimum DC-DC convertor output voltage with 250 mW output power.

Board Thermal Optimization

Board layout can be optimized for thermal performance if necessary. A double sided, double buried power plane ("2s2p") board maximizes thermal performance. Thermal vias should be used between the power plane and the board surfaces. All of the IC ground pins should be connected, with wide traces to help cool the leadframe.

Maintaining Creepage

Creepage distances are often critical in isolated circuits. In addition to meeting JEDEC standards, NVE isolator packages have unique creepage specifications. Standard pad libraries often extend under the package, compromising creepage and clearance. Similarly, ground planes, if used, should be spaced to avoid compromising clearance. Package drawings and recommended pad layouts are included in this datasheet.

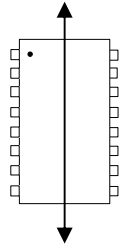
Inherently Low EMI

IL76xx-Series parts designed for compliance with IEC 61000-6-3, IEC 61000-6-4, CISPR, and FCC Class A standards for emissions. The DC-DC convertor oscillator operates above 88 MHz, where emission limits are higher since there is less risk of interference with common commercial radio and television broadcasting.

Frequency-hopping technology dramatically reduces peak EMI, and synchronous rectification and PWM control are avoided, resulting in inherently low EMI. Ferrite beads are generally not required for EMI mitigation.

High Magnetic Immunity

These parts are fully compliant with IEC 61000-6-1 and IEC 61000-6-2 magnetic immunity standards. The coupler’s Wheatstone bridge configuration and differential magnetic field signaling ensure excellent EM immunity. Immunity to external magnetic fields is even higher if the field direction is “end-to-end” (rather than to “pin-to-pin”) as shown at right.



Typical Performance Graphs

The following graphs show typical performance:

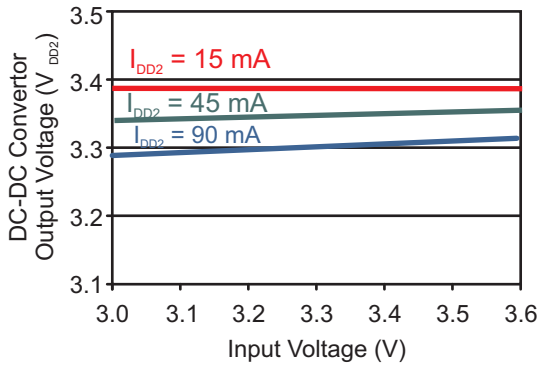


Figure 3. Typical DC-DC converter line regulation.

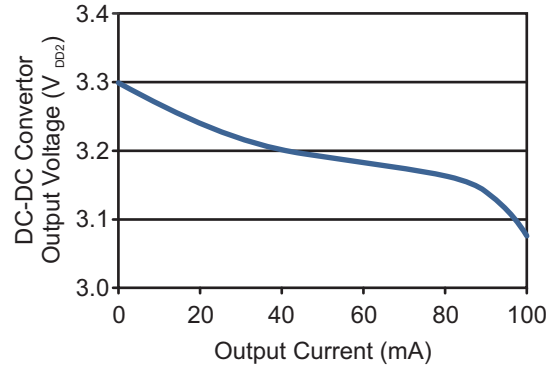


Figure 4. Typical DC-DC converter load regulation ($V_{DD1} = 3.3$ V).

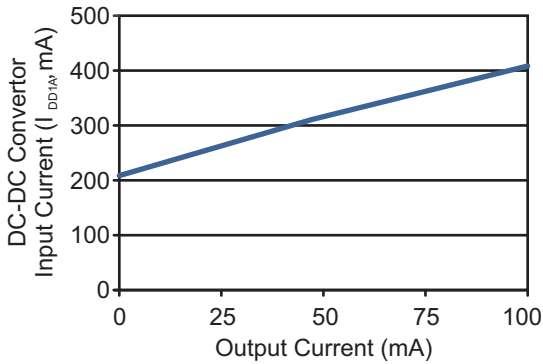


Figure 5. Typical DC-DC converter supply current versus output current ($V_{DD1} = 3.3$ V).

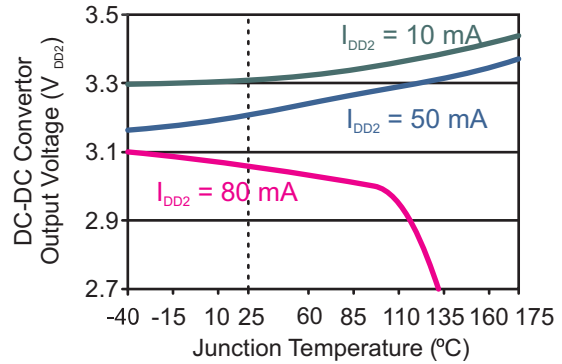


Figure 6. Typical DC-DC converter output versus temperature ($V_{DD1A} = 3.3$ V).

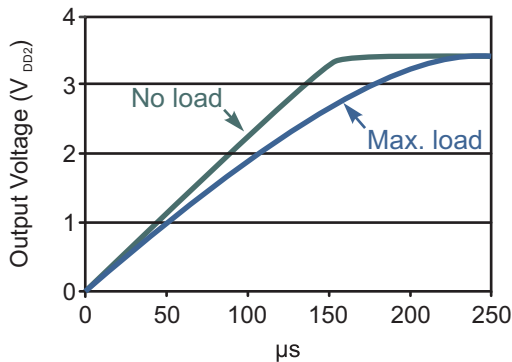


Figure 7. Typical DC-DC converter startup.

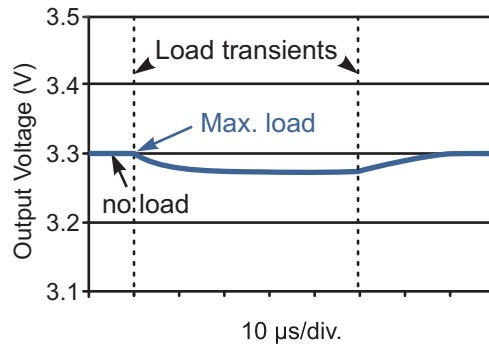


Figure 8. DC-DC converter transient response.

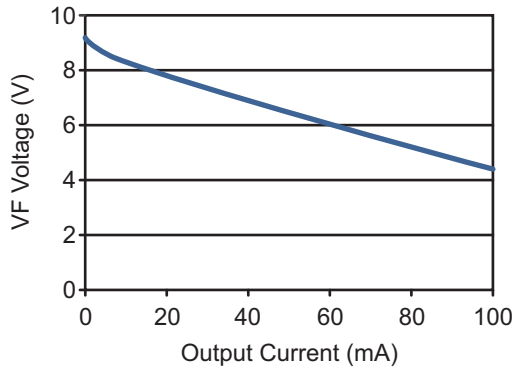


Figure 9. Typ. VF output vs. output current ($V_{DD1A} = 3.3\text{ V}$; $25\text{ }^{\circ}\text{C}$).

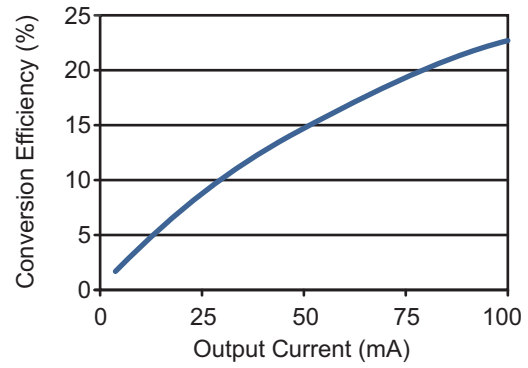


Figure 10. Typ. DC-DC converter power efficiency ($V_{DD1A} = 3.3\text{ V}$; $25\text{ }^{\circ}\text{C}$).

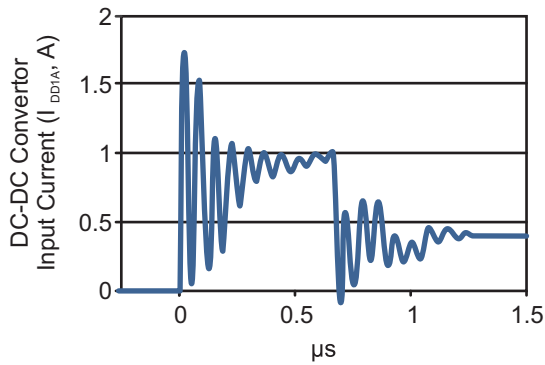


Figure 11. Typical start-up current (max. load; no V_{DD1} bypass capacitor).

Typical Applications

Isolated SPI interface to ADC:

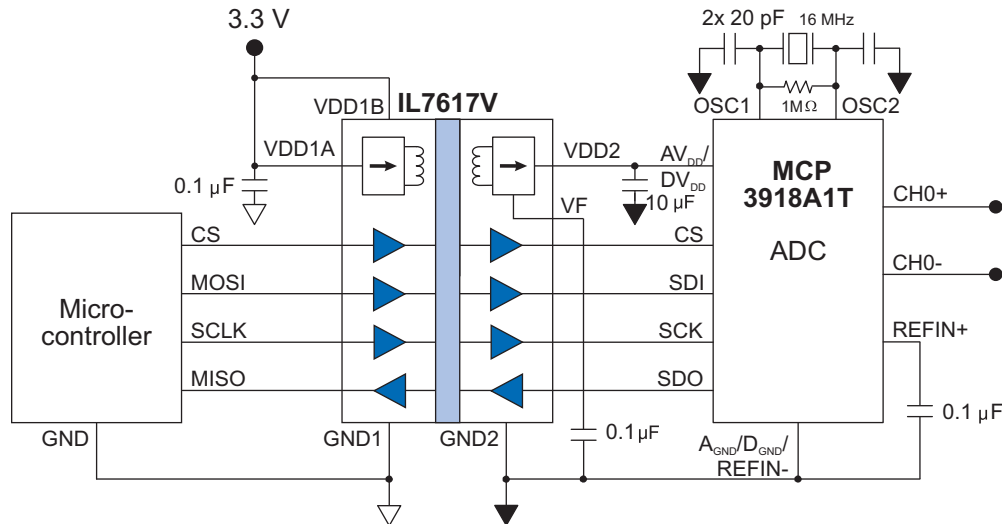


Figure 11. Isolated bidirectional SPI ADC interface.

The IL7617VE provides three transmit and one receive channel, making it ideal for isolating ubiquitous bidirectional SPI peripherals such as ADCs. The isolation allows safe connections to line voltage, and the isolated power supply prevents microcontroller noise from affecting the ADC.

Isolated SPI sensor interface:

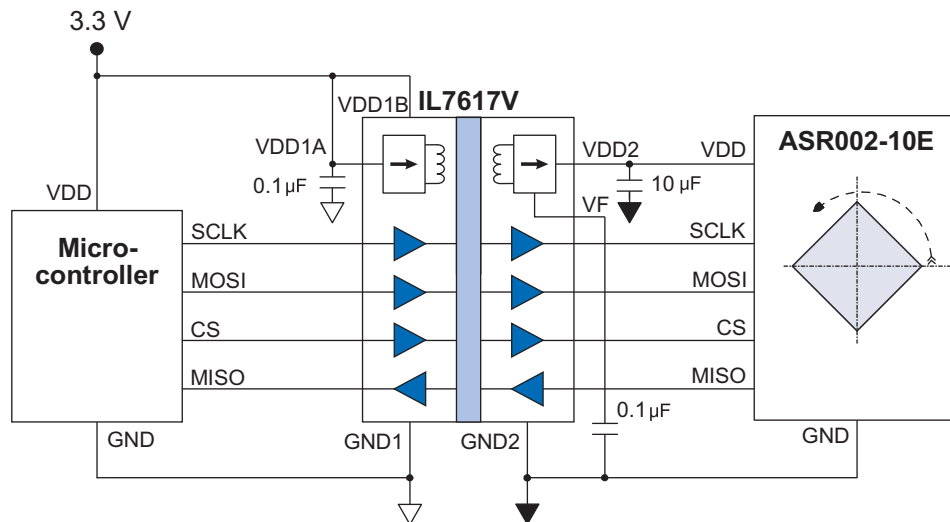


Figure 12. Isolated SPI sensor interface.

The IL7617VE provides three transmit and one receive channel, making it ideal for isolating classic SPI sensors. The isolated power supply prevents noise from the microcontroller from affecting the sensor.

Isolated SPI / MICROWIRE interface to transmit-only ADC:

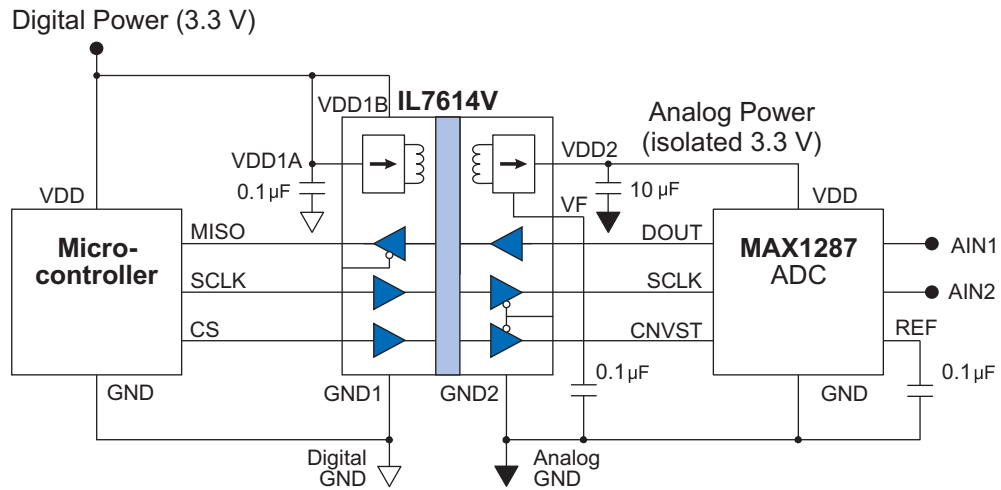


Figure 13. Isolated ADC serial interface.

Only three channels of isolation are required for transmit-only SPI peripherals such as ADCs or sensors. The IL7614VE provides an isolated analog power supply to significantly improve the noise performance of a successive-approximation ADC, and also isolates the serial interface.

Isolated shunt-based electric meter interface:

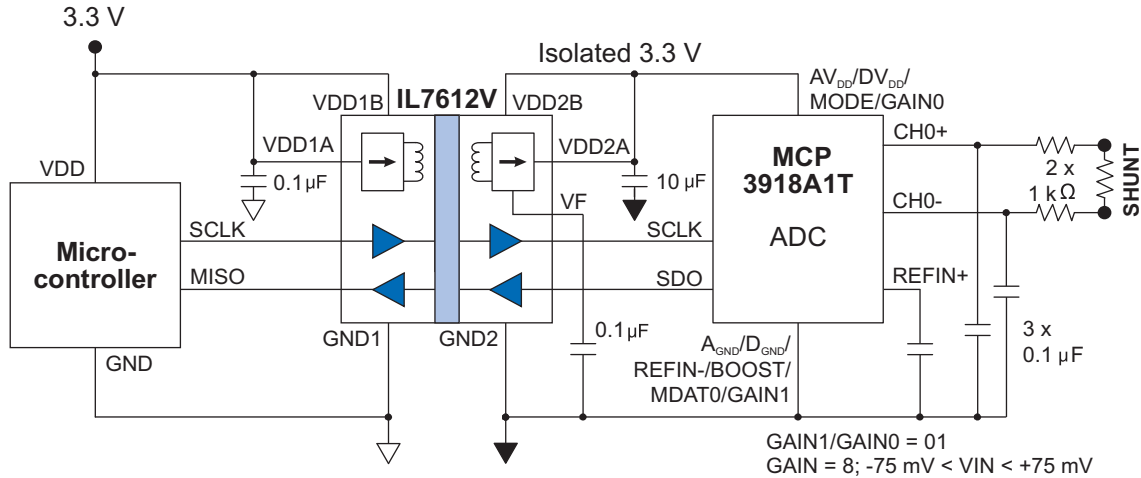


Figure 14. Isolated shunt-based current sensing.

Just two channels are needed to isolate unidirectional SPI-type interfaces that do not have chip-selects or other interface lines. The circuit above takes advantage of the “two-wire interface mode” of an MCP3918 ADC. The IL7612VE also supplies ADC power for shunt-based current sensing in the circuit above for power measurement systems such as electric meters. Unlike most optocouplers, the IL7612VE isolator section is fast enough for the ADC’s 20 MHz high-speed SPI.

Isolated SPI for receive-only DACs:

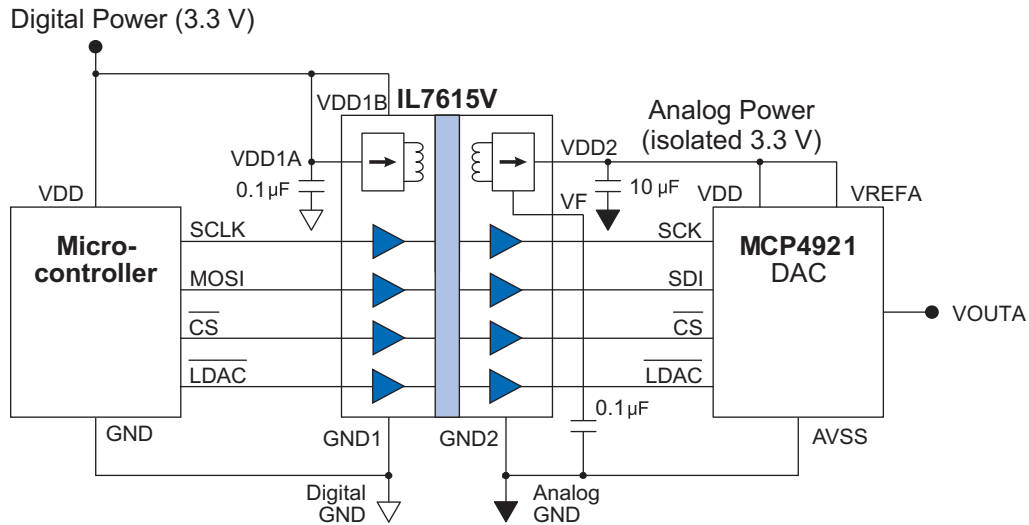


Figure 15. Isolated four-channel DAC interface.

The IL7615V provides four transmit channels of isolation for receive-only DACs with SPI plus additional lines. In the example above, the LDAC synchronization line is isolated, which transfers data from the serial interface latches to the output latches, as well as the SPI lines (SCLK, MOSI, and CS).

Double-isolated parallel DAC interface:

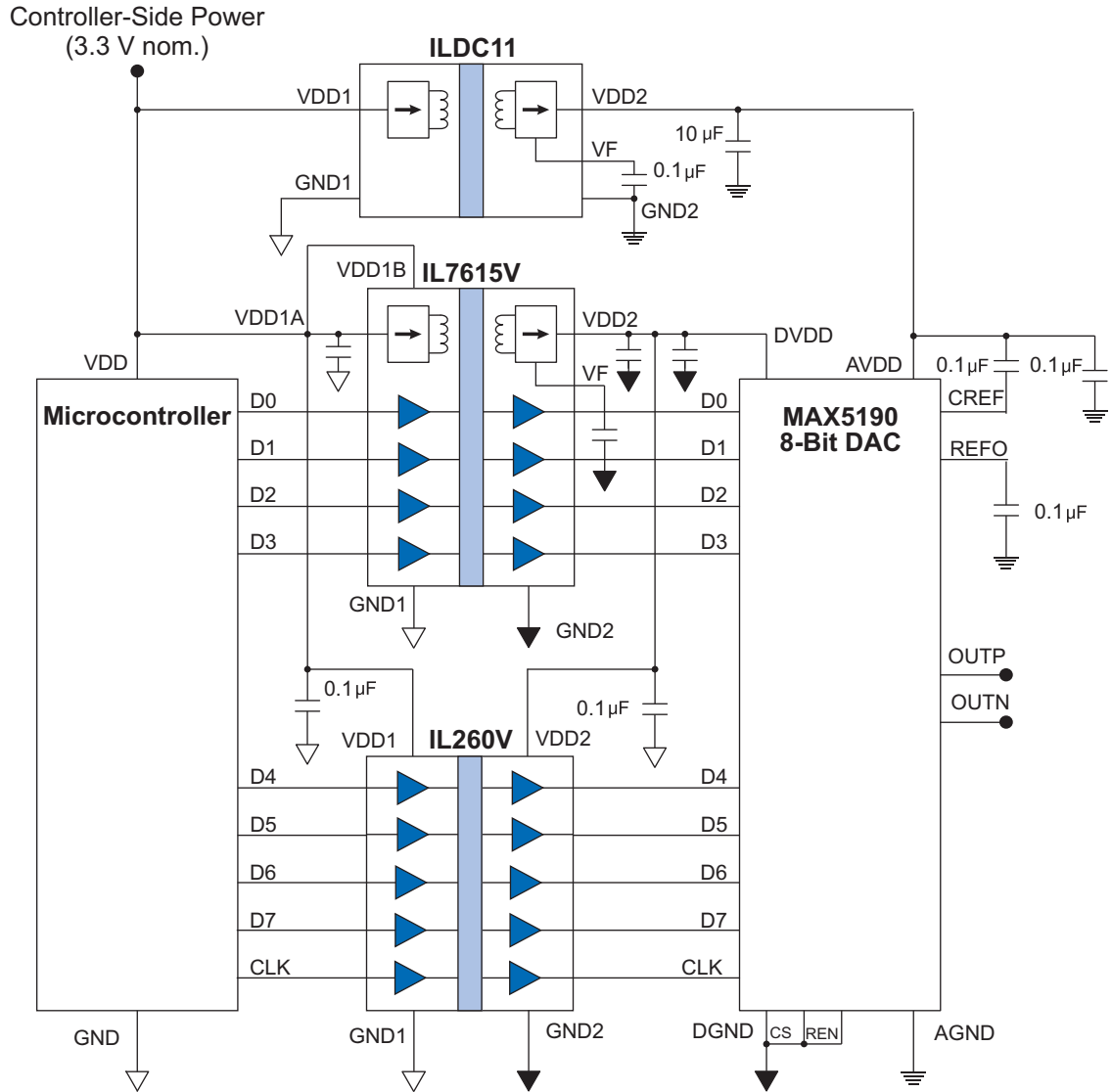


Figure 16. Double-isolated parallel DAC interface.

The IL7615V plus an IL260V provide isolated digital power and nine channels of isolation. This allows isolation of an eight-bit parallel peripheral such as a high-speed digital-to-analog converter. The 110 Mbps speed of the IL7615V and IL260V couplers support the 40 MHz DAC used in this circuit. A separate ILDC11 DC-DC converter provides an isolated analog power supply to improve noise performance by preventing digital noise from affecting the analog section of the DAC. The ILDC11's extremely low ripple also enhances the DAC's noise performance.

Isolated interface to multiple SPI sensors:

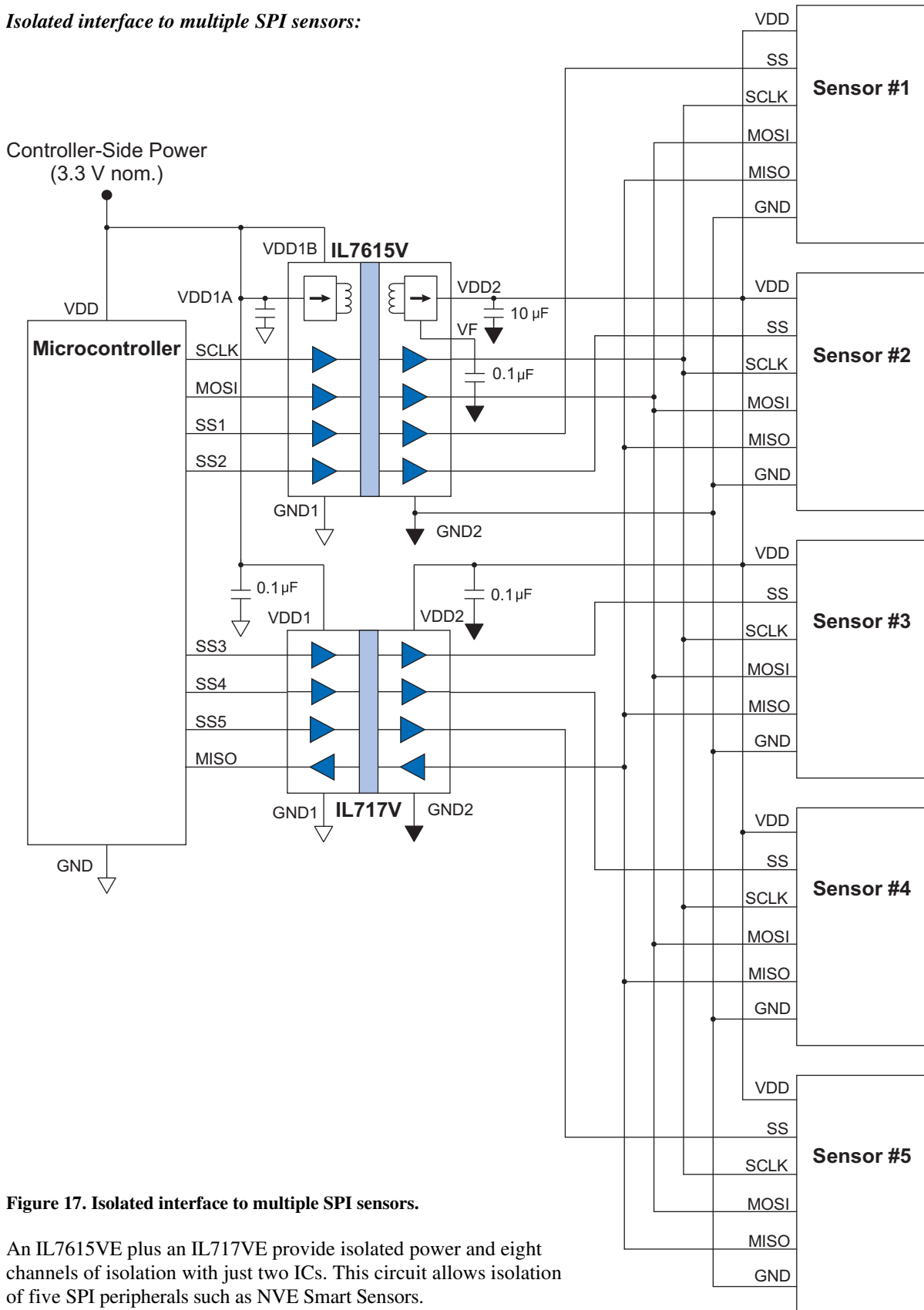
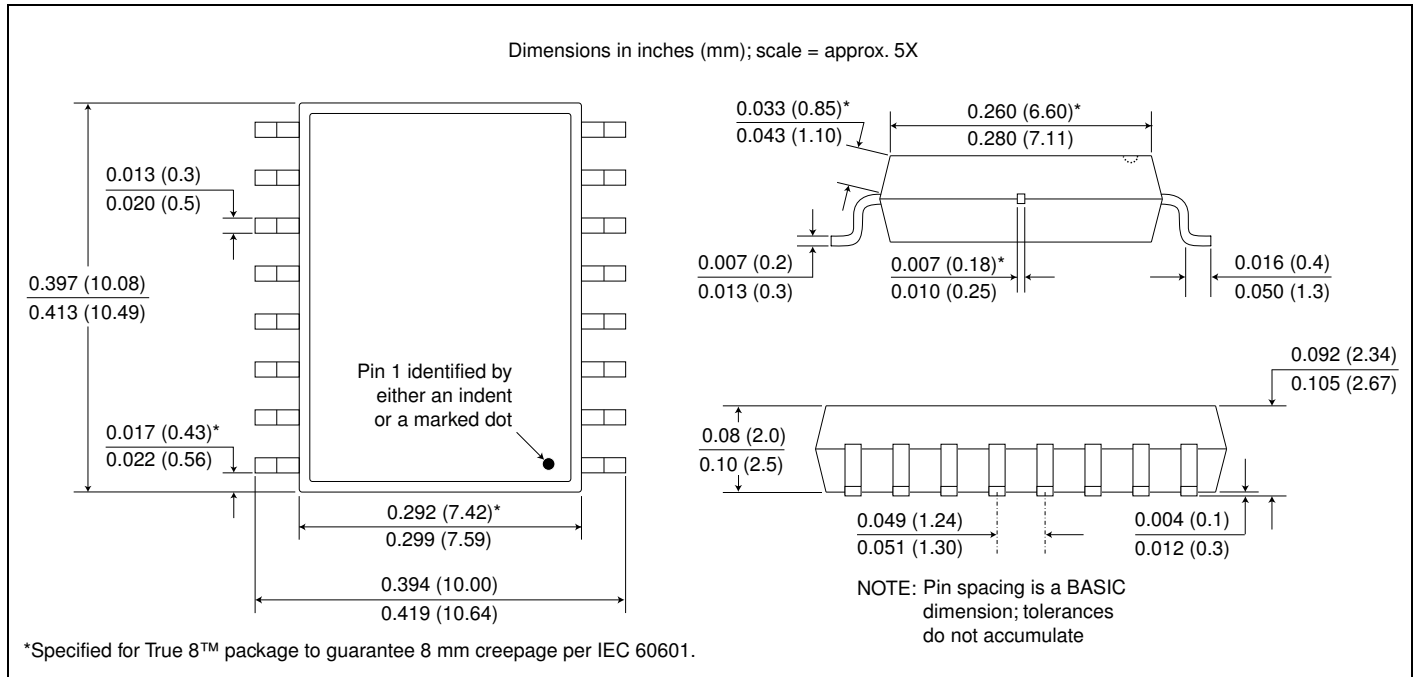


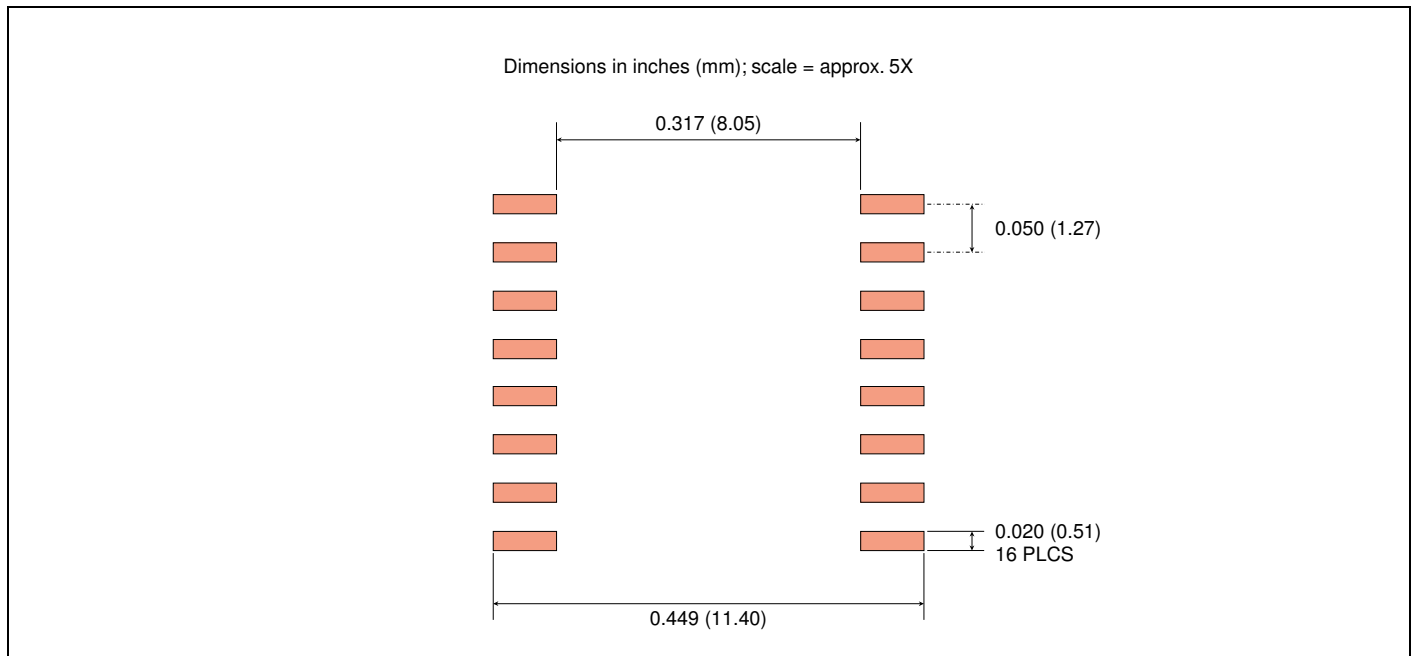
Figure 17. Isolated interface to multiple SPI sensors.

An IL7615VE plus an IL717VE provide isolated power and eight channels of isolation with just two ICs. This circuit allows isolation of five SPI peripherals such as NVE Smart Sensors.

Package Drawing



Recommended Pad Layout



Available Part Numbers

Part Number	Channels (transmit/receive)	Bulk Packaging	RoHS?
IL7611VE	2 / 0	Tubes (50 pcs.)	RoHS
IL7612VE	1 / 1		
IL7614VE	2 / 1		
IL7615VE	4 / 0		
IL7616VE	2 / 2		
IL7617VE	3 / 1		
IL7611VE-TR7	2 / 0	7-inch reels (up to 450 pcs.)	
IL7612VE-TR7	1 / 1		
IL7614VE-TR7	2 / 1		
IL7615VE-TR7	4 / 0		
IL7616VE-TR7	2 / 2		
IL7617VE-TR7	3 / 1		
IL7612VE-TR13	1 / 1	13-inch reels (up to 1500 pcs.)	
IL7614VE-TR13	2 / 1		
IL7614VE-TR13	2 / 1		
IL7615VE-TR13	4 / 0		
IL7616VE-TR13	2 / 2		
IL7617VE-TR13	3 / 1		
IL7611V	2 / 0	Tubes (50 pcs.)	SnPb finish (non-RoHS; Special Order)
IL7612V	1 / 1		
IL7614V	2 / 1		
IL7615V	4 / 0		
IL7616V	2 / 2		
IL7617V	3 / 1		
IL7611V-TR7	2 / 0	7-inch reels (up to 450 pcs.)	
IL7612V-TR7	1 / 1		
IL7614V-TR7	2 / 1		
IL7615V-TR7	4 / 0		
IL7616V-TR7	2 / 2		
IL7617V-TR7	3 / 1		
IL7611V-TR13	2 / 0	13-inch reels (up to 1500 pcs.)	
IL7612V-TR13	1 / 1		
IL7614V-TR13	2 / 1		
IL7615V-TR13	4 / 0		
IL7616V-TR13	2 / 2		
IL7617V-TR13	3 / 1		

Revision History

ISB-DS-001-IL76xx-Rev. B
September 2021

Changes

- Corrected IL7616V (p. 5) and IL7617V (p. 6) pin-out diagrams.
- Changed isolation voltage to 4 kV under the more stringent IEC60747-17 standard.

ISB-DS-001-IL76xx-Rev. A
April 2021

Changes

- Added IL7611V and IL7612V.
- Changed Absolute Maximum storage and junction temperatures to 150 °C.
- Added VF vs. output current typical performance graph.
- Added descriptions of external regulator options.
- Added IL7617V / ADC application circuit (Figure 11).
- Added IL7612V / ADC application circuit (Figure 14).
- Added IL7615V / DAC application circuit (Figure 15).

ISB-DS-001-IL76xx-PRELIM3
August 2020

Changes

- Added thermal shutdown protection (p. 9) and graph (Figure 6).
- Added start-up current specification (p. 6) and typical graph (Figure 9).

ISB-DS-001-IL76xx-PRELIM2
July 2020

Change

- Added IL7616 and IL7617.

ISB-DS-001-IL76xx-PRELIM
July 2020

Change

- Preliminary release.

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September 2021